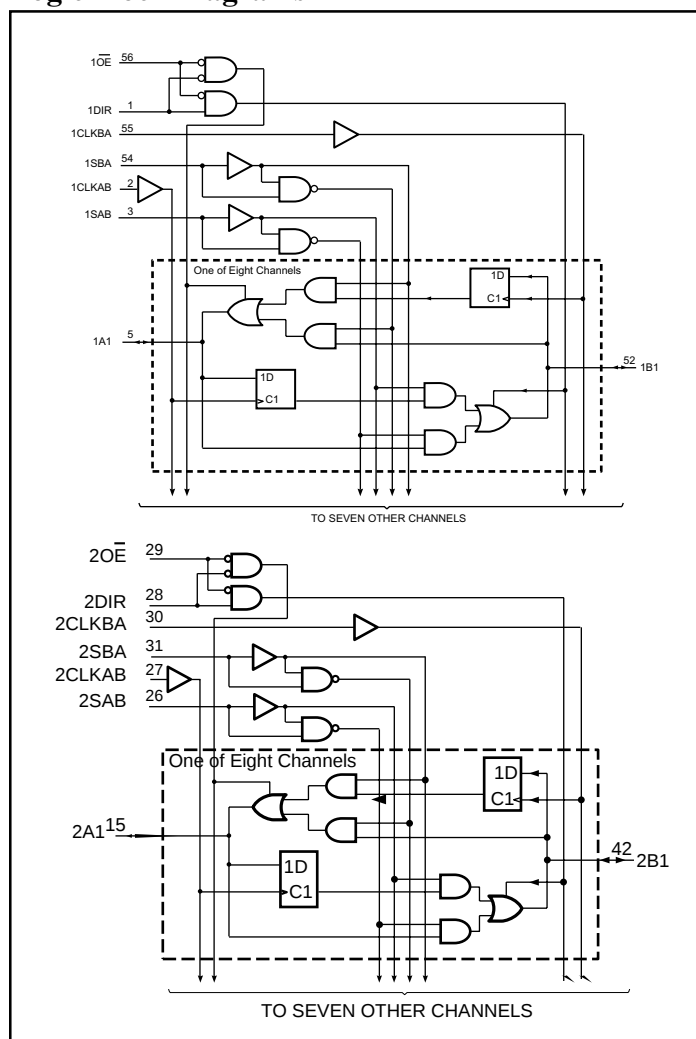


2.5V 16-Bit Bus Transceiver and Register with 3-State Outputs

Product Features

- PI74ALVTC16646 is designed for low voltage operation, $V_{DD} = 1.65V$ to $3.6V$
- Supports Live Insertion
- 3.6V I/O Tolerant Inputs and Outputs
- Bus Hold
- High Drive, $-32/64mA @ 3.3V$
- Uses patented noise reduction circuitry
- Power-off high impedance inputs and outputs
- Industrial operation at $-40^{\circ}C$ to $+85^{\circ}C$
- Packages available:
 - 56-pin 240-mil wide plastic TSSOP (A56)
 - 56-pin 173-mil wide plastic TVSOP (K56)

Logic Block Diagrams



Product Description

Pericom Semiconductor's PI74ALVTC series of logic circuits are produced using the Company's advanced 0.35 micron CMOS technology, achieving industry leading speed.

The PI74ALVTC16646 is a 16-bit bus transceiver and register designed for 1.65V to 3.6V V_{CC} operation. It can be used as two 8-bit transceivers or one 16-bit transceiver. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate Clock (CLKAB or CLKBA) input. Four fundamental bus-management functions can be performed.

Output Enable ($\overline{OE}$) and Direction Control (DIR) inputs are provided to control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either register or in both. The Select Control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. Circuitry used for Select Control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. DIR determines which bus receives data when $\overline{OE}$ is LOW. In the isolation mode ($\overline{OE}$ HIGH), A data may be stored in one register and/or B data may be stored in the other register.

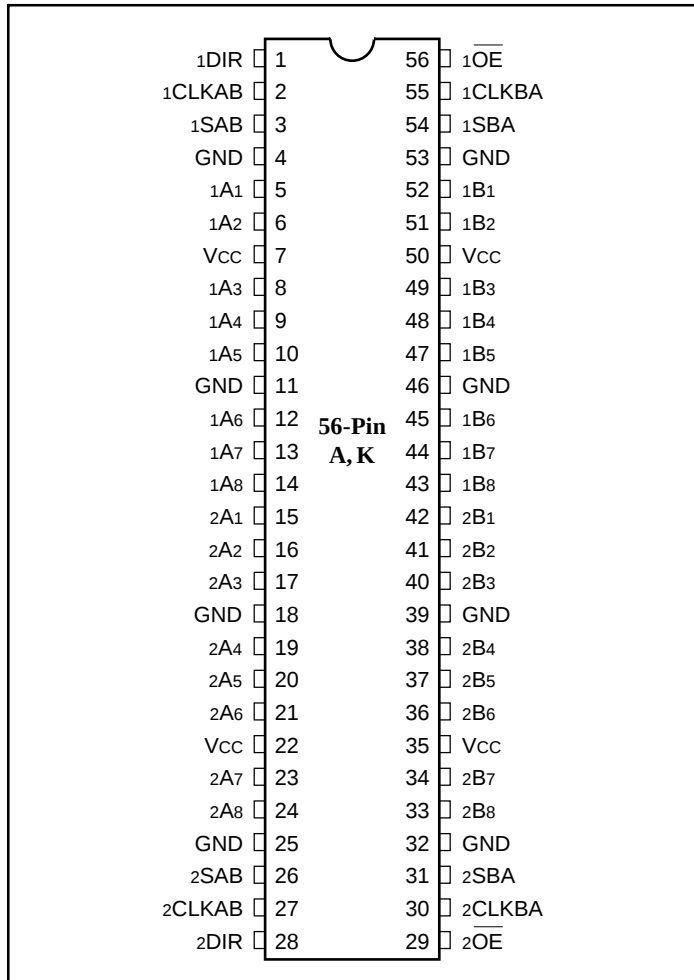
When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two buses, A or B, can be driven at a time.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The family offers both I/O Tolerant, which allows it to operate in mixed 1.65/3.6V systems, and "Bus Hold," which retains the data input's last state preventing "floating" inputs and eliminating the need for pullup/down resistors.

Pin Configuration



Product Pin Description

Pin Name	Description
xOE	Output Enable Inputs (Active LOW)
xDIR	Direction Control
xCLKAB, xCLKBA	Clock Pulse Inputs
xSAB, xSBA	Select Control Inputs
xAx	Data Register A Inputs Data Register B Outputs
xBx	Data Register B Inputs Data Register A Outputs
GND	Ground
VCC	Power

Truth Table

Function	Inputs						Data I/O	
	xOE	xDIR	xCLKAB	xCLKBA	xSAB	xSBA	xAx	xBx
Store A, B Unspecified ⁽¹⁾	X	X	↑	X	X	X	Input	Unspecified ⁽¹⁾
Store B, A Unspecified ⁽¹⁾	X	X	X	↑	X	X	Unspecified ⁽¹⁾	Input
Isolation, Hold Storage	H	X	H or L	H or L	X	X	Input Disable	Input Disable
Store A and B Data	H	X	↑	↑	X	X	Input	Input
Real Time A Data to B Bus	L	H	X	X	L	X	Input	Output
Stored A Data to B Bus	L	H	H or L	X	H	X	Input	Output
Real Time B Data to A Bus	L	L	X	X	X	L	Output	Input
Stored B Data to A Bus	L	L	X	H or L	X	H	Output	Input

Notes:

- The data output functions may be enabled or disabled by various signals at the xOE or xDIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs.
- H = High Voltage Level
X = Don't Care
L = Low Voltage Level
↑ = LOW-to-HIGH transition

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply Voltage Range, V_{DD}	-0.5V to 4.6V
Input Voltage Range, V_I	-0.5V to 4.6V
Output Voltage Range, V_O (3-States)	-0.5V to 4.6V
Output Voltage Range, $V_O^{(1)}$ (Active)	-0.5V to $V_{DD}+0.5V$
DC Input Diode Current (I_{IK}) $V_I < 0V$	-50mA
DC Output Diode Current (I_{OK})	
$V_O < 0V$	-50mA
$V_O > V_{DD}$	±50mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	-64/128mA
DC V_{DD} or GND Current per Supply Pin (I_{CC} or GND)	±100mA
Storage Temperature Range, T_{stg}	-65°C to 150°C

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions⁽²⁾

			Min.	Max.	Units
V_{DD}	Supply voltage	Operating	1.65	3.6	V
		Data Retention Only	1.2	3.6	
V_{IH}	High-level input voltage	$V_{DD} = 2.7V$ to $3.6V$	2.0		
V_{IL}	Low-level input voltage	$V_{DD} = 2.7V$ to $3.6V$		0.8	
V_I	Input voltage		-0.3	3.6	
V_O	Output voltage	Active State	0	V_{DD}	mA
		Off State	0	3.6	
	Output current in I_{OH}/I_{OL}	$V_{DD} = 3.0V$ to $3.6V$		-32/64	
		$V_{DD} = 3.0V$ to $3.6V$		±24	
		$V_{DD} = 2.3V$ to $2.7V$		±18	
		$V_{DD} = 1.65V$ to $1.95V$		±6	
$\Delta t/\Delta v$	Input transition rise or fall rate ⁽³⁾		0	10	ns/V
T_A	Operating free-air temperature		-40	85	C

Notes:

1. Absolute maximum of I_O must be observed.
2. Unused control inputs must be held HIGH or LOW to prevent them from floating.
- 3 As measured between 0.8V and 2.0V, $V_{DD}=3.0V$.

Electrical Characteristics over Recommended Operating Free-Air Temperature Range
(unless otherwise noted)

DC Characteristics (2.7V < V_{DD} ≤ 3.6V)

	Parameter	Conditions	V _{DD}	Min.	Typ.	Max.	Units
V _{IK}	Input Clamp Diode	I _{IK} = -18mA	3.0			-1.2	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100μA	2.7 - 3.6	V _{DD} - 0.2			
		I _{OH} = -12mA	2.7	2.2			
		I _{OH} = -18mA	3.0	2.4			
		I _{OH} = -24mA		2.2			
		I _{OH} = -32mA		2.0			
V _{OL}	LOW Level Output Voltage	I _{OL} = 100μA	2.7 - 3.6			0.2	
		I _{OL} = 12mA	2.7			0.4	
		I _{OL} = 18mA	3.0			0.4	
		I _{OL} = 24mA				0.45	
		I _{OL} = 32mA				0.5	
		I _{OL} = 64mA				0.75	
I _I	Input Leakage Current	V _I = V _{DD} , or GND	3.6			±5.0	μA
I _{OZ}	3-State Output Leakage	V _O = 3.6V	2.7			±10	
I _{OFF}	Power-OFF Leakage Current	V _I or V _O ≤ 3.6V	0			10	
I _{HOLD}	Bus Hold Current A or B Outputs	V _I = 0.8V	3.0	75			
		V _I = 2.0V		-75			
		V _I = 0 to 3.6V	3.6			±500	
I _{DD}	Quiescent Supply Current	V _I = V _{DD} or GND	2.7 - 3.6			50	
		V _{DD} ≤ (V _I , V _O) ≤ 3.6V				±50	
ΔI _{DD}	Increase in I _{DD} per input	V _{IH} = V _{DD} - 0.6V, Other inputs at V _{DD} or Gnd				400	

Notes:

1. All unused inputs must be held at V_{CC} or GND to ensure proper device operation.

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted; continued from previous page)

DC Characteristics ($2.3V \leq V_{DD} \leq 2.7V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	2.3			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	2.3 - 2.7	$V_{DD} - 0.2$			
		$I_{OH} = -12mA$	2.3	1.8			
		$I_{OH} = -18mA$		1.7			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$	2.3 - 2.7			0.2	
		$I_{OL} = 12mA$	2.3			0.4	
		$I_{OL} = 18mA$				0.5	
		$I_{OL} = 24mA$				0.55	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	2.7			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	2.3			± 10	
I_{OFF}	Power-OFF Leakage Current	V_I or $V_O \leq 3.6V$	0			10	
$I_{HOLD}^{(1)}$	Bus Hold Current A or B Outputs	$V_I = 0.7V$	2.5		90		μA
		$V_I = 1.7V$			-90		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	2.3 - 2.7			40	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 40	
ΔI_{DD}	Increase in I_{DD} per input	$V_{IH} = V_{DD} - 0.6V$, Inputs at V_{DD} or Gnd				400	

Note:

1. Not Guaranteed

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted; continued from previous page)

DC Characteristics ($1.65V \leq V_{DD} \leq 1.95V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	1.65			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	1.65-1.95	$V_{DD} - 0.2$			
		$I_{OH} = -6mA$	1.65	1.4			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$				0.2	
		$I_{OL} = 6mA$				0.3	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	1.95			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	1.65			± 10	
I_{OFF}	Power-OFF Leakage Current	$V_I = V_O \leq 3.6V$	0			10	
$I_{HOLD}^{(1)}$	Bus Hold Current A or B Outputs	$V_I = 0.4$	1.65		50		
		$V_I = 1.3$			-50		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	1.65-1.95			20	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 20	
ΔI_{DD}	Increase in I_{DD} per input	$V_I = V_{DD} - 0.6V$, Other inputs at V_{DD} or Gnd				400	

Note:

1. Not Guaranteed

Timing Requirements (Over recommended operating free-air temperature range, unless otherwise noted, see Figures 1 thru 4)

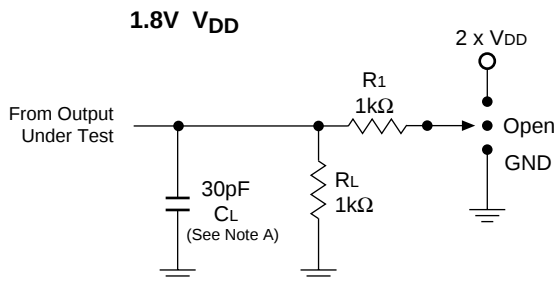
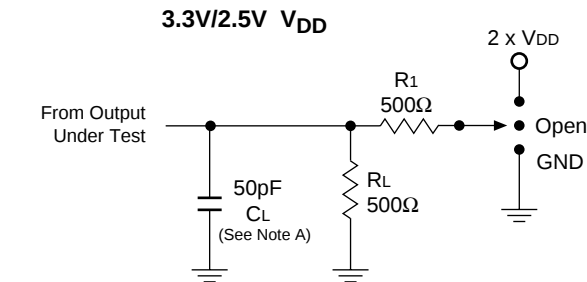
	V_{CC} = 1.8V ±0.15V		V_{CC} = 2.5V ±0.2V		V_{CC} = 3.3V ±0.3V		Units
	Min.	Max.	Min.	Max.	Min.	Max.	
f _{clock} Clock Frequency		150		180		180	MHz
t _w Pulse duration, CLKAB or CLKBA high or low	2.0		1.5		1.5		ns
t _{su} Setup time, A before CLKAB↑, or B before CLKBA↑	1.8		1.4		1.2		
t _h Hold time, A after CLKAB↑, or B after CLKBA↑	1.0		0.7		0.5		

Switching Characteristics (Over recommended operating free-air temperature range, unless otherwise noted, see Figures 1 thru 4)

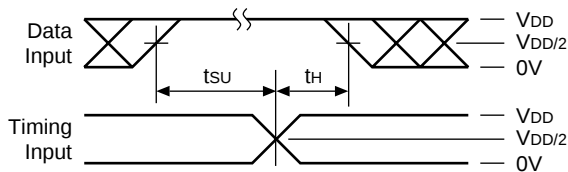
Parameters	From (Input)	To (Output)	V _{CC} = 1.8V ±0.15V		V _{CC} = 2.5V ±0.2V		V _{CC} = 3.3V ±0.3V		Units	
			Min.	Max.	Min.	Max.	Min.	Max.		
f _{max}			150		180		180		MHz	
t _{pd}	A or B	B or A	1.0	5.0	1.0	4.0	1.0	3.4	ns	
	CLKAB or CLKBA	A or B	1.1	5.5	1.0	4.5	1.0	3.3		
	SAB or SBA		1.3	6.0	1.1	5.3	1.0	3.8		
t _{en}	OE		1.2	5.8	1.0	5.0	1.0	4.0		
t _{dis}			1.3	6.1	1.0	4.7	1.2	5.0		
t _{en}	DIR		1.0	5.2		4.7	1.0	4.0		
t _{djs}			1.7	6.4		4.4	1.0	4.2		

Test Circuits and Switching Waveforms

Parameter Measurement Information ($V_{DD} = 1.65V - 3.6V$)



Setup, Hold, and Release Timing



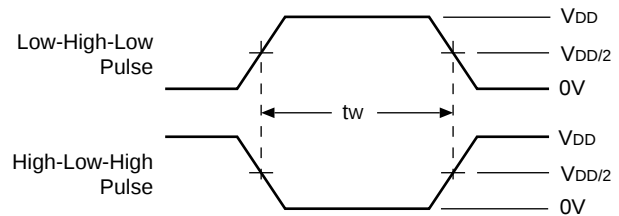
Notes:

- C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50\Omega$, $t_r \leq 2\text{ns}$, $t_f \leq 2\text{ns}$, **measured from 10% to 90%, unless otherwise specified.**
- The outputs are measured one at a time with one transition per measurement.

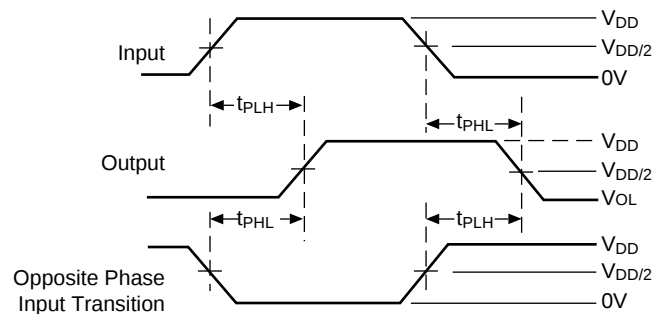
Switch Position

Test	S1
t_{PD}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{DD}$
t_{PHZ}/t_{PZH}	GND

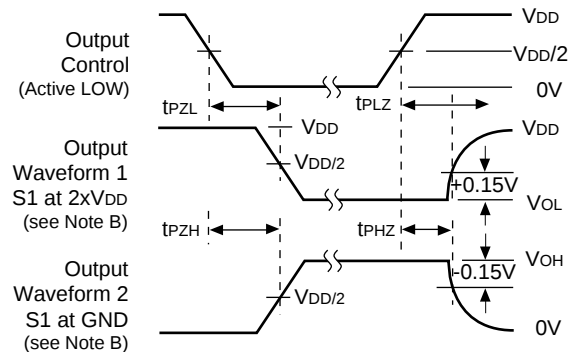
Pulse Width

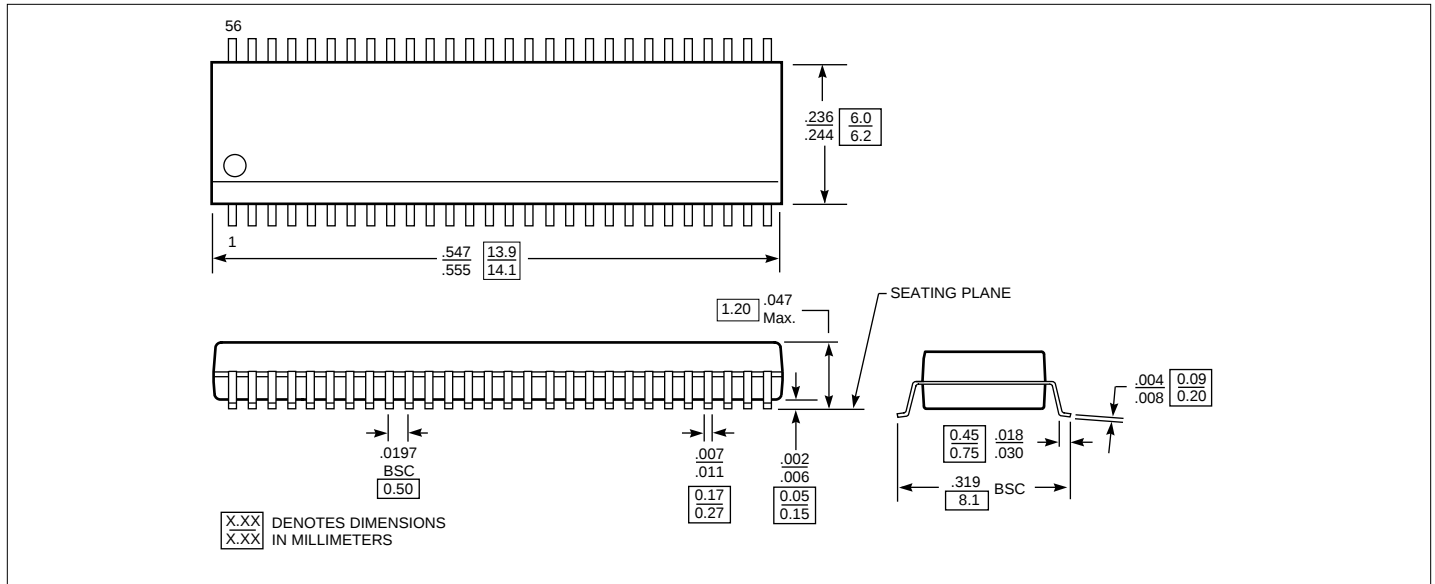
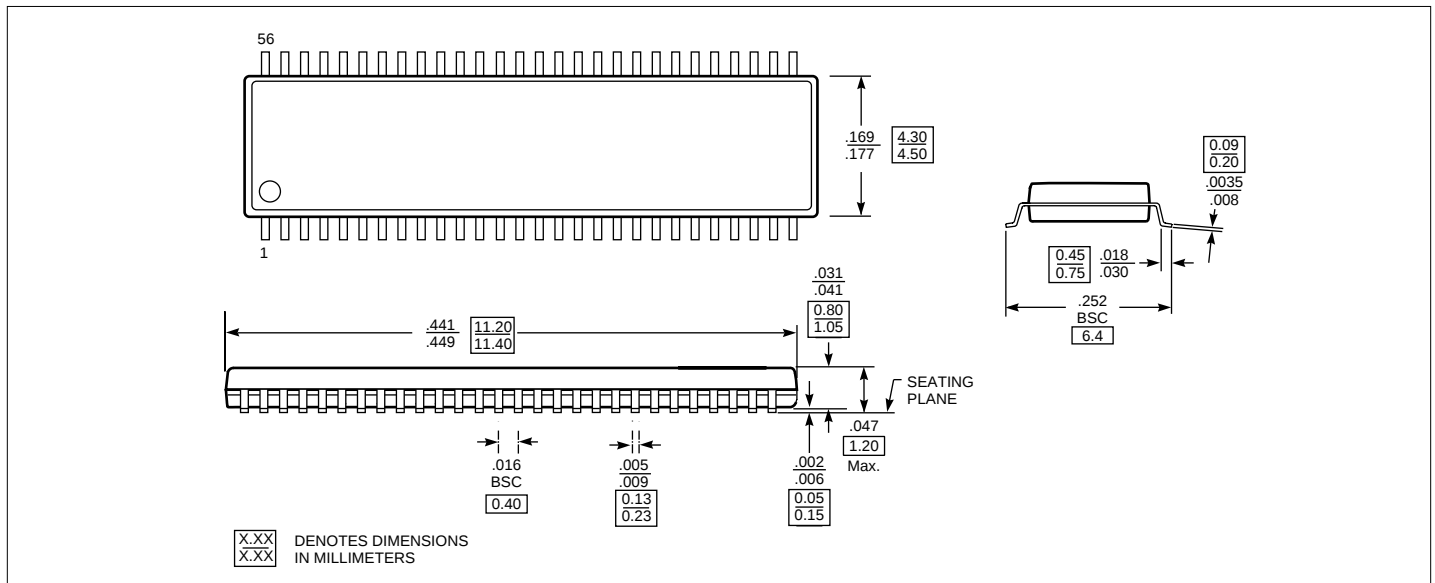


Propagation Delay



Enable Disable Timing



Packaging Mechanical: 56-pin TSSOP (A)

Packaging Mechanical: 56-pin TVSOP (K)


Ordering Information	Package - Pins
PI74ALVTC16646A	TSSOP - 56
PI74ALVTC16646K	TVSOP - 56